

Filterless 8W Class- F Audio Amplifier

General Description

The LPA2174 is a 8W, class-F audio amplifier with a mode pin for switch the work mode. It offers low THD+N, allowing it to achieve high-quality Power Supply sound reproduction. The new filterless architecture allows the device to drive the speaker directly requiring no low-pass output filters, thus to save the system cost and PCB area. The LPA2174 is available in ESOP-8.

Order Information



Applications

- ♦ Portable Bluetooth Speaker
- ♦ Cellular and Smart mobile phone
- ♦ Square Speaker

Features

- Shutdown current:<5uA
- 500KHz fixed frequency switching for amplifier
- 8W Output at 10% THD with a 2Ω Load and 6.0V VDD for amplifier
- 3.4W Output at 10% THD with a 4Ω Load and 5V VDD for amplifier
- 2.7W Output at 1% THD with a 4Ω Load and 5V VDD for amplifier
- Filterless, Low Quiescent Current and Low EMI
- Amplifier Efficiency up to 85%
- Free LC filter digital modulation, direct-drive speakers
- Short Circuit Protection
- Thermal Shutdown
- Few external components to save the space and cost
- Pb-Free Package

Typical Application Circuit



Marking Information

Device	Marking	Package	Shipping			
	LPS		4K/REEL			
LPA2174SPF	LPA2174	ESOP-8				
	YWX					
Y: Y is year code. W: W is week code. X: X is series number.						

PowerSemi



Pin Configuration

Package Type	Pin Configurations				
ESOP-8	BYP 1 8 SD MODE 2 GND 7 VON VIN 3 9 6 VDD VIP 4 5 VOP				

Functional Pin Description

Pin	PIN No.	DESCRIPTION					
BYP	1	Bypass pin (Connect a 0.22uF capacitor between this pin and GND).					
MODE	2	Mode control pin (High voltage with Class_D mode and low voltage with Class_AB mode).					
VIN	3	Negative input of amplifier.					
VIP	4	Positive input of amplifier.					
VOP	5	Positive output of signal.					
VDD	6	Voltage supply pin.					
VON	7	Negative output of signal.					
SD	8	Shutdown pin (active high).					
GND	9(PAD)	Ground pin.					

Absolute Maximum Ratings

Input Voltage to GND0.3V to 7.4	5V
Other pin to GND0.3V to 6.	.5V
Lead Temperature (Soldering, 10 sec.) 260	°C
Storage Temperature Range65°C to 165	°С
Operation Junction Temperature Range	°C
Operation Ambient Temperature Range	°C
Maximum Power Dissipation (PD,TA<40°C)2.6Thermal resistance (junction to ambient)	SW W



Electrical Characteristics For Amplifier

(VDD = 5V, RL=4 Ω , TA = 25° C, unless otherwise specified)

		Test Conditions			Тур			
Parameter	Symbol			Min	Class-	Class-	Max	Units
					D	AB		
Supply power	VIN			2.5			6.5	V
			VDD=6.5V		5.7	5.7		
			VDD=5.5V		4.2	4.2		
		$f = 1KH_7 PI = 40$	VDD=5.0V		3.3	3.3		
		1- INI12,NL-492	VDD=4.2V		2.3	2.3		
			VDD=3.6V		1.7	1.7		
			VDD=6.5V		4.6	4.6		
			VDD=5.5V		3.3	3.3		
		1HD+N=1%,	VDD=5.0V		2.7	2.7		
		$T = T K H Z, K L = 4 \Omega$	VDD=4.2V		1.8	1.8		
			VDD=3.6V		1.4	1.4		
			VDD=6.0V		8	8		
	Po	THD+N=10%, f=1KHz,RL=2Ω	VDD=5.5V		6.7	6.7		
Output power			VDD=5.0V		5.5	5.5		W
			VDD=4.2V	旧子	3.3	3.9		
			VDD=3.6V	11/25	2.3	2.9		
		THD+N=10%, f=1KHz,RL=8Ω	VDD=6.0V		2.2	2		
			VDD=5.5V		1.8	1.5		
			VDD=5.0V		1.5	1.4		
			VDD=4.2V		1.1	1.1		
			VDD=3.6V		0.8	0.8		
			VDD=6.0V		1.8	1.7		
			VDD=5.5V		1.5	1.3		
		THD+N=1%,	VDD=5.0V		1.2	1.2		
		t=1KHZ,RL=8Ω	VDD=4.2V		0.8	0.8		
			VDD=3.6V		0.6	0.6		
Power supply ripple		INPUT ac-grounded with	f=100HZ		7	5		
rejection	PSRR	CIN=0.47uF, VDD=6.0V	f=1KHz		5	50		dB
Signal-to-noise ratio		VDD=5V,Class_AB	f=1KHz		g)1		
	SNR	VDD=5V,Class_D	f=1KHz		g	0		dB
Output noise VN		INPUT ac-grounded with		1(00		μV	
Efficiency	η	RL=4Ω, Po=3.2W f=1KHz			84			%
VOS		VDD=5.0V, VSD =0V	VDD=5.0V, VSD =0V		1.1	2.5		mV



Preliminary Datasheet

LPA2174

Threshold voltage of MODE	VMOD_D	VDD=2.5-6.5V		75%VDD				V
	VMOD_A	VDD=2.5-6.5V					50%VDD	V
Threshold voltage of shutdown pin	VSD_H	VSD_H VDD=2.5-6.5V 1.4				V		
	VSD_L	VDD=2.5-6.5V					0.4	V
Shutdown current ILEAK		VSD =VDD=5.0V			2	2		uA
Quiescent current	IQ	VDD=5.0V	No load		4	6.8		mA

Typical Operating Characteristic





A-A FREQ RESP FAST @ 40hm PO=4.8W CLASS AB VDD=6V.ats2





Audio Precision



A-A FREQ RESP FAST @ 4ohm PO=4.8W CLASS D VDD=6V.ats2

Audio Precision

A-A THD+N vs FREQUENCY



included in the measurement bandwidth. For band-limited systems IMD testing is better.

A-A THD+N VS FREQ @4ohm PO=3W CLASS D VDD=6V.ats2

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Preliminary Datasheet

LPA2174

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A-A THD+N vs FREQUENCY



A-A THD+N VS FREQ @4ohm PO=3W CLASS AB VDD=6V.ats2

Audio Precision

2

1

Green

Solid



3

Analyzer.THD+N Ratio A

Left

6V 4ohm Class AB



Audio Precision







Sweep	Trace	Color	Line Style	Thick	Data	Axis	Comment
1	1	Green	Solid	3	Analyzer.THD+N Ratio A	Left	6V 2ohm Class D
2	1	Yellow	Solid	3	Analyzer.THD+N Ratio A	Left	6V 20hm Class AB

Applications Information

Maximum Gain

The LPA2174 has two internal amplifier stages. The first stage's gain is externally configurable, while the second stage's is internally fixed. The closed-loop gain of the first stage is set by selecting the ratio of Rf to Ri while the second stage's gain is fixed at 2x. The output of amplifier serves as the input to amplifier 2, thus the two amplifiers produce signals identical in magnitude, but different in phase by 180°. Consequently, the differential gain for the IC is

Av=20log [2*(Rf/Ri)]

The LPA2174 sets maximum:

 Rf= 280 k Ω±10%
 Class-AB

 Rf= 280 k Ω±10%
 Class-D

Shutdown operation

In order to reduce power consumption while not in use, the LPA2174 contains shutdown circuitry to turn off the amplifier's bias circuitry. This shutdown feature turns the amplifier off when logic high is applied to the SD pin. By switching the SD pin connected to high voltage, the LPA2174 supply current draw will be minimized in idle mode.

Power supply decoupling

The LPA2174 is a high performance CMOS audio amplifier that requires adequate power supply decoupling to ensure the output THD and PSRR a low as possible. Power supply decoupling affects low frequency response. Optimum decoupling is achieved by using two capacitors of different types targeting to different types of noise on the power supply leads. For higher frequency transients, spikes, or digital hash on the line, a good low equivalent-series-resistance (ESR) ceramic capacitor, typically 1.0μ F, works best, placing it as close as possible to the device VDD terminal. For filtering lower- frequency noise signals, a large capacitor of 20μ F (ceramic) or greater is recommended, placing it near the audio power amplifier.

Over Temperature Protection

Thermal protection on the LPA2174 prevents the device from

damage when the internal die temperature exceeds 150°C. Once the die temperature exceeds the thermal set point, the device outputs are disabled. This is not a latched fault. The thermal fault is cleared once the temperature of the die is reduced by 30°C. This large hysteresis will prevent motor boating sound well and the device begins normal operation at this point without external system intervention.

Analog Reference Bypass Capacitor (CBYP)

In addition to system cost and size, click and pop performance is affected by the size of the input coupling capacitor, CBYP. A larger input coupling capacitor requires more charge to reach its quiescent DC voltage (nominally 1/2 VDD). This charge comes from the internal circuit via the feedback and is apt to create pops upon device enable. Thus, by minimizing the capacitor size based on necessary low frequency response, turn-on pops can be minimized.

The Analog Reference Bypass Capacitor (CBYP) is the most critical capacitor and serves several important functions. During start-up or recovery from shutdown mode, CBYP determines the rate at which the amplifier starts up. The second function is to reduce noise caused by the power supply coupling into the output drive signal. This noise is from the internal analog reference to the amplifier, which appears as degraded PSRR and THD+N.

How to reduce EMI

A simple solution is to put an additional capacitor 220pF at power supply terminal for power line. The traces from amplifier to speakers should design as short as we can.





Packaging Information





Preliminary Datasheet





SYMBOLS	DIMENSI	ON (MM)	DIMENSION (INCH)		
STIVIDOLS	MIN	MAX	MIN	MAX	
А	1.30	1.70	0.051	0.067	
A1	0.00	0.15	0.000	0.006	
A2	1.25	1.52	0.049	0.060	
b	0.33	0.51	0.013	0.020	
С	5.80	6.20	0.228	0.244	
D	4.80	5.00	0.189	0.197	
D1	3.15	3.45	0.124	0.136	
E	3.80	4.00	0.150	0.157	
E1	2.26	2.56	0.089	0.101	
е	1.27 BSC		0.050	0 BSC	
Н	0.19	0.25	0.0075	0.0098	
L	0.41	1.27	0.016	0.050	
θ	0°	8°	0°	8°	